

# NPN SILICON RF TRANSISTOR

**DESCRIPTION:**

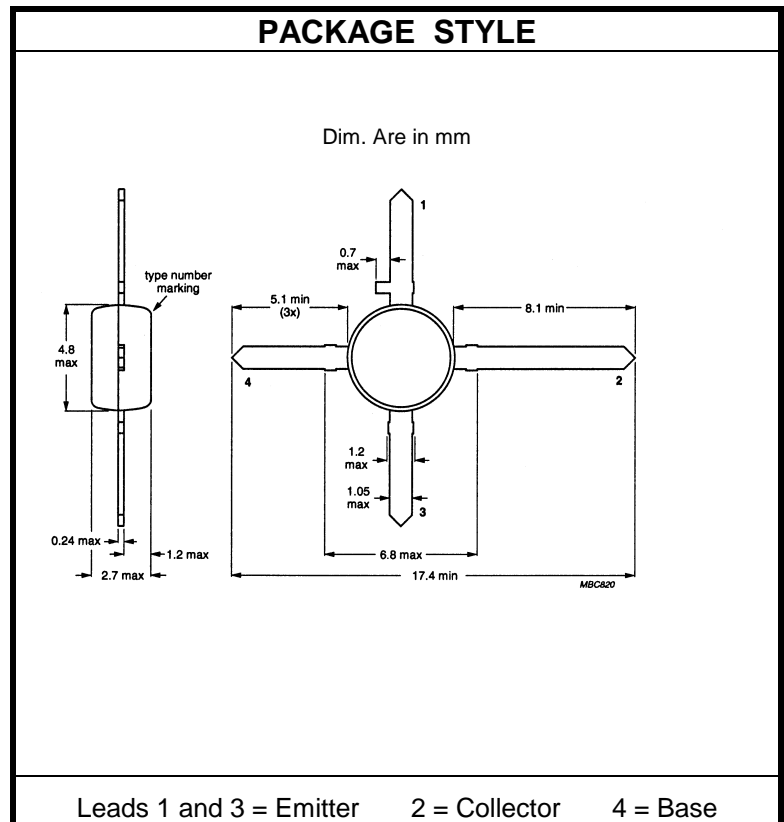
The **ASI MRF951** is Designed for high gain. Low noise small-signal amplifiers. Applications up to 2.0 GHz.

**FEATURES:**

- Low Noise Figure
- High Gain
- **Omnigold™** Metalization System

**MAXIMUM RATINGS**

$I_C$	100 mA
$V_{CBO}$	20 V
$V_{CEO}$	10 V
$V_{EBO}$	1.5 V
$P_{DISS}$	1.0 W @ $T_C = 25\text{ }^\circ\text{C}$
$T_J$	-65 °C to +150 °C
$T_{STG}$	-65 °C to +150 °C
$\theta_{JC}$	100 °C/W


**CHARACTERISTICS**  $T_C = 25\text{ }^\circ\text{C}$ 

SYMBOL	TEST CONDITIONS			MINIMUM	TYPICAL	MAXIMUM	UNITS
$BV_{CBO}$	$I_C = 0.1\text{ mA}$			20			V
$BV_{CEO}$	$I_C = 0.1\text{ mA}$			10			V
$I_{CBO}$	$V_{CB} = 10\text{ V}$					0.1	$\mu\text{A}$
$I_{EBO}$	$V_{EB} = 1.0\text{ V}$					0.1	$\mu\text{A}$
$h_{FE}$	$V_{CE} = 6.0\text{ V}$	$I_C = 5.0\text{ mA}$		50		200	---
$C_{cb}$	$V_{CB} = 10\text{ V}$	$f = 1.0\text{ MHz}$			0.45		pF
$G_{NF}$	$V_{CE} = 6.0\text{ V}$	$I_C = 5.0\text{ mA}$	$f = 1.0\text{ GHz}$		14		dB
			$f = 2.0\text{ GHz}$		9.0		
$NF_{50\Omega}$	$V_{CE} = 6.0\text{ V}$	$I_C = 5.0\text{ mA}$			1.9	2.8	dB

# Mouser Electronics

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